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- \* Indicates key paper.
- # Indicates the presence of a phase diagram.

Ge-Pr evaluation contributed by **A.B. Gokhale, A. Munitz,** and **G.J. Abbaschian**, Department of Materials Science and Engineering, University of Florida, Gainesville, FL 32611. This work was supported by ASM INTERNATIONAL under grant No. FG101-1. Thermodynamic calculations were made using the F\*A\*C\*T\* computer program at the McGill University, Montreal, Quebec, Canada. The evaluators wish to thank Dr. K.A. Gschneidner, Jr., Director, Rare Earth Information Center, Iowa State University, for his help in providing some of the literature sources. Literature searched through 1984. Professor Abbaschian is the ASM/NIST Data Program Category Editor for binary germanium alloys.

# The Nd-Si (Neodymium-Silicon) System

By A.B. Gokhale, A. Munitz, and G.J. Abbaschian University of Florida

### Equilibrium Diagram

The assessed Nd-Si equilibrium diagram is shown in Fig. 1, and the monovariant and invariant equilibria are summarized in Table 1.

A complete investigation of the phase equilibria in the Nd-Si system was carried out by [84Ere], employing metallographic, X-ray diffraction and differential thermal analysis measurements. The assessed equilibrium diagram is based primarily on the work of [84Ere], with modifications incorporated on the basis of other studies on the synthesis and physical properties of various intermediate phases.

The important characteristics of the system can be summarized as follows:

- Tetragonal Nd5Si3 is the richest in Nd in the system, forming peritectically at 1447 °C. [84Ere] indicated the phase to be nearly stoichiometric. However, based on the lattice parameter data of [68Ram], a homogeneity range of 1 at.% Si is indicated tentatively in this evaluation.
- Nearly stoichiometric, tetragonal Nd5Si4 forms peritectically at 1567 °C.
- Nearly stoichiometric, orthorhombic NdSi melts congruently at 1677 °C.

- Nearly stoichiometric, Nd3Si4 forms peritectoidally at 1397 °C; the structure has not been determined.
- Nearly stoichiometric, Nd2Si3 (reported as NdSi1.5 by [84Ere]) forms peritectoidally at 1507 °C and undergoes an allotropic transformation at 527 °C. The low-temperature modification is hexagonal, whereas the high-temperature structure remains undetermined.
- NdSi<sub>x</sub> (reported as NdSi<sub>1.8</sub> by [84Ere]) melts congruently at 1757 °C. [84Ere] indicated a homogeneity range of 64 to 65 at.% Si for the phase. However, based on the synthesis data of [65Dvo1], [65Dvo2], [65Sam], and [66Dvo], the range has been extended to 66.79 at.% Si in this evaluation. [84Ere] indicated an allotropic transformation at 147 °C on the Si-deficient side (64 at.% Si) and at 97 °C on the Si-rich side (65 at.% Si), with an orthorhombic, aGdSi2-type low-temperature modification; they did not identify the high-temperature form, designated  $\beta NdSi_x$  in this evaluation. The allotropic transformation temperature at the Si-rich limit (66.79 at.% Si) has been calculated to be 7.5 °C, using a linear extrapolation of the allotropic transformation data of [84Ere]. The high-temperature modification is indicated to be tetragonal,  $\alpha$ ThSi<sub>2</sub>-type, based on the data of [68Ram]. [60Bin] noted that the melting temperature of



1050

1000

950

900

863\*0

850

800

750

Nd

ပ္

Temperature

1021°C

ßNd)

837°C

792\*

ĥ

Atomic Percent Silicon

A.B. Gokhale, A. Munitz, and G.J. Abbaschian, 1989.

8

L

10.5

10 12

12.5

14

In addition, in this evaluation, the melting temperatures of the pure components have been revised to conform with the currently accepted values [86Gsc]. A catatectic (inverse peritectic) reaction involving the  $\alpha \leftrightarrow \beta$  transformation of Nd has been included: [84Ere] indicated an allotropic transformation temperature for Nd of 837 °C, which is significantly different from the currently accepted value of 863 °C. The catatectic reaction, shown schematically on an expanded scale in Fig. 2, indicates a 26 °C depression in the allotropic transformation temperature of Nd due to the addition of Si.

The Nd-Si liquidus was determined reliably by [84Ere]. Because no thermodynamic data on the properties of the liquid solution are available in the literature, they were assessed in this evaluation using the experimental solubility data of [84Ere]; the mixing process was found to be slightly endothermic.

The mutual solid solubility limits of Si and Nd have not been reported. Based on the interaction of Si with other rare earths, the solubilities are probably negligible, as indicated in Fig. 1.

# Nd-Si

| Table 1 | Monovariant and Invariant Nd-Si Equ | uilibria |
|---------|-------------------------------------|----------|
|---------|-------------------------------------|----------|

| Reaction   | Compositions<br>of the respective pha<br>at.% Si | <b>BCS</b> , | Temperature,<br>°C | Reaction type             |  |
|--|--|--------------|--------------------|---------------------------|--|
| $L \leftrightarrow \beta Nd$   | 0  |              | 1021 (a)           | Melting point             |  |
| $\beta Nd \leftrightarrow \alpha Nd$   | 0  |              | 863 (a)            | Allotropic transformation |  |
| $(\beta Nd) \leftrightarrow (\alpha Nd) + L$   | 0  | 10.5         | 837 (b)            | Catatectic                |  |
| $L \leftrightarrow (\alpha Nd) + Nd_5Si_3 12.5$  | 0  | 37           | 792                | Eutectic                  |  |
| $L + Nd_5Si_4 \leftrightarrow Nd_5Si_3$  | 44.45  | 37.5         | 1447               | Peritectic                |  |
| $L + NdSi \leftrightarrow Nd_5Si_4$  | 50   | 44.45        | 1567               | Peritectic                |  |
| L ↔ NdSi   | 50   |              | 1677               | Congruent point           |  |
| $L \leftrightarrow NdSi + \beta NdSi_x$  | 50   | 64           | 1577               | Eutectic                  |  |
| NdSi + $\beta$ Nd <sub>2</sub> Si <sub>3</sub> $\leftrightarrow$ Nd <sub>3</sub> Si <sub>4</sub> | 60   | 57.14        | 1397               | Peritectoid               |  |
| NdSi + $\beta$ NdSi <sub>x</sub> $\leftrightarrow \beta$ Nd <sub>2</sub> Si <sub>3</sub>         | 64   | 60           | 1507               | Peritectoid               |  |
| $\alpha Nd_2Si_3 \leftrightarrow \beta Nd_2Si_3$   | 60   |              | 527                | Allotropic transformation |  |
| $L \leftrightarrow \beta NdSi_x$   | 65.4   |              | 1757               | Congruent point           |  |
| $L \leftrightarrow \beta NdSi_x + (Si) \dots 83$   | 66.79  | 100          | 1197               | Eutectic                  |  |
| $\alpha NdSi_x \leftrightarrow \beta NdSi_x$   | 62 to 66.79                                      |              | 147 to 7.5         | Allotropic transformation |  |
| L ↔ Si   | 100  |              | 1414 (c)           | Melting point             |  |
| From [84Ere]. (a) [86Gsc]. (b) This work   | . (c) [Melt].                                    |              |                    |                           |  |

## Table 2 Nd-Si Crystal Structure Data

| Phase                                     | Composition,<br>at.% Si | Pearson<br>symbol | Space<br>group | Struktur-<br>bericht<br>designation | Prototype        |  |
|---|-------------------------|-------------------|----------------|-------------------------------------|------------------|--|
| βNd (a)                                   | 0                       | cI2               | Im∃m           | A2                                  | W                |  |
| αNd (b)                                   | 0                       | hP4               | P63/mmc        | A3'                                 | αLa              |  |
| Nd5Si3                                    | ~ 37 to ~ 38            | tI32              | I4/mcm         | $D8_1$                              | $Cr_5B_3$        |  |
| Nd5Si4                                    | 44.55                   | •••               | $P4_{1}2_{1}2$ | •••                                 | Zr5Si4           |  |
| NdSi                                      | 50                      | 0 <b>P</b> 8      | Pnma           | B27                                 | FeB              |  |
| Nd3Si4                                    | 57.14                   |                   |                | •••                                 |                  |  |
| aNd2Si3                                   | 60                      | hP3               | P6/mmm         | C32                                 | AlB <sub>2</sub> |  |
| βNd <sub>2</sub> Si <sub>3</sub>          | 60                      | •••               | ••••           |                                     | -                |  |
| αNdSi <sub>x</sub>                        | 64 to 66.79             |                   | Imma           |                                     | aGdSi2           |  |
| βNdSi <sub>x</sub>                        | 64 to 66.79             | tI12              | $I4_1/amd$     | $C_{c}$                             | aThSi2           |  |
| Si  | 100                     | cF8               | Fd3m           | A4                                  | C(diamond)       |  |
| (a) From 1021 to 863 °C. (b) From 863 °C. |                         |                   |                |                                     |                  |  |

#### Table 3 Nd-Si Lattice Parameter Data at 24 °C

|                    | Composition,      | Latt            | ice parameters, n | m         | Refer       | ences                                 |
|--------------------|-------------------|-----------------|-------------------|-----------|-------------|---------------------------------------|
| Phase              | at.% Si           | a               | т b               | C         | Primary     | Supplementary                         |
| BNd                | . 0               | 0.413           |                   |           | [86Gsc] (a) |                                       |
| αNd                | . 0               | 0.36582         | •••               | 1.17966   | [86Gsc]     | [King1]                               |
| Nd5Si3             | . ~37             | 0.770(5)        |                   | 1.370(1)  | [68Ram]     |                                       |
|                    | 37.5              | 0.7674          |                   | 1.3852    | [84Ere]     | [69May 72 May]                        |
|                    |                   | 0.7787          | •••               | 1.373     | [72May] (b) | · · · · · · · · · · · · · · · · · · · |
|                    | ~ 38              | 0.7745(5)       |                   | 1.383(1)  | [68Ram]     |                                       |
| Nd5Si4             | . 44.45           | 0.7843          |                   | 1 4818    | [84Ere]     | [67Smi, 68Ram]                        |
| NdSi               | . 50              | 0.8756(5)       | 0.32920(3)        | 0.5881(3) | [66Hoh]     | [64Gla, 65Par,<br>68Ram, 84Erel       |
| Nd3Si4             | . 57.14           |                 |                   |           |             |                                       |
| aNd2Si3            | . 60              | 0.3940(5)       |                   | 0.4258(5) | [68Ram]     | [84Ere]                               |
| BNd2Si3            | . 60              |                 |                   |           |             | []                                    |
| αNdSix             | . 64              | 0.4133          | 0.4099            | 1.3731    | [84Ere]     |                                       |
|                    | 65                | 0.4176          | 0.4145            | 1.3599    | [84Ere]     |                                       |
|                    | 66.67             | 0.418           | 0.415             | 1.356     | [60Bin]     | [67Mav]                               |
| BNdSix             | . 66.67           | 0.4162(5)       |                   | 1.358(1)  | [67Ram]     | [51Bra, 68Ram]                        |
| Śi                 | . 100             | 0.54306         | •••               |           | [King1]     | , <b>voiva</b>                        |
| (a) Measurement as | t 883 °C. (b) Mea | asurements at 2 | 280 °C.           |           | -           |                                       |

Table 4 Crystal Structure and Lattice Parameter Data for NdSi<sub>x</sub> (1.63  $\leq x \leq$  2.01)

|   | Latti        | Lattice parameters, nm     |                 |                      |                                |             |
|---|--------------|----------------------------|-----------------|----------------------|--------------------------------|-------------|
| Prototype                                     | a            | - b                        | С               | nm <sup>3</sup>      | Comment                        | Reference   |
| $\overline{\alpha \text{ThSi}_2(\mathbf{a})}$ | 0.4111       |                            | 1.356           | 0.22917              | At 66.67 at .%Si               | [51Bra]     |
|   | •••          |                            | •••             |                      | At 66.67 at.% Si               | [58Mat]     |
|   | 0.4162       |                            | 1.358           | 0.23524              | At 66.67 at.% Si               | [67Ram]     |
|   |              |                            |                 |                      | At 66.67 at.% Si               | [68May] (c) |
| $\alpha GdSi_2(b)$                            | 0.418        | 0.415                      | 1.356           | 0.23523              | At 66.67 at .%Si               | [60Bin]     |
|   | 0.417        | 0.413                      | 1.365           | 0.23508              | At 66.67 at.% Si               | [67May]     |
|   | 0.4125       | 0.4095                     | 1.371           | 0.23159              | <66.67 at.% Si                 | [68Ram]     |
|   | 0.4176       | 0.4145                     | 1.3599          | 0.23539              | At 65 at.% Si                  | [84Ere]     |
|   | 0.4133       | 0.4099                     | 1.3731          | 0.23262              | At 64 at.% Si                  | [84Ere]     |
| (a) Tetragonal. (b                            | ) Orthorhomb | ic or distorted $\alpha$ 7 | hSi2. (c) Noted | that the structure i | s $lpha ThSi_2$ type at 1600 ° | C.          |



#### **Intermediate Phases**

Physical properties for  $NdSi_x$  (NdSi<sub>2</sub>) have been reported in the literature. The phase, with electrical resistivity of 27  $\mu\Omega$ -cm, and a microhardness of 698  $\pm$ 10 kg/mm<sup>2</sup>[65Sam, 66Dvo2] does not exhibit a superconducting transition down to 1 K [58Mat]. [72May] reported thermal expansion coefficients for the phase as follows:

 $\alpha a = 9.8 \times 10^{-6}/\mathrm{K}$ 

and

 $\alpha c = 11.0 \times 10^{-6}/\mathrm{K}$ 

where  $\alpha_a$  and  $\alpha_c$  are the thermal expansion coefficients in the *a* and *c* directions, respectively.

## **Crystal Structures and Lattice Parameters**

Selected Nd-Si crystal structure and lattice parameter data are summarized in Tables 2 and 3. The data are taken from references listed under "primary reference," chosen on the basis of thoroughness of investigation, listing of diffraction data, and agreement with other investigations; other pertinent reference are listed under "supplementary references."

The crystal structure and lattice parameter(s) of Nd3Si4 have not been determined. The reported data for other intermediate phases show good agreement, except in two instances: (1)For Nd5Si3, [69Nar] reported a wrong prototype (Mn5Si3, instead of Cr5B3), and thus a wrong space group. Their lattice parameter data are therefore not considered in this evaluation; and (2)The crystal structure and lattice parameter data for  $NdSi_x$  are somewhat conflicting with regard to the crystal type present, and they show a variation in the lattice parameters for the same crystal type. The conflict apparently stems from three factors-NdSix exhibits a rather wide homogeneity range, the allotropic transformation temperature changes with Si contents (Fig. 3), and the transformation is of a displacive type and thus is difficult to measure accurately [59Per].

It should be noted that the structural change in NdSix from  $\alpha$ GdSi2 type to  $\alpha$ ThSi2 type is accompanied by only small changes in the volume of the unit cell. Further, the  $\alpha$  and b dimensions for the  $\alpha$ GdSi2 type are only slightly different. Also, as mentioned above, if the allotropic transformation temperature data of [84Ere] are extrapolated linearly to the Si-rich limit of the phase, a transformation temperature of 7.5 °C is obtained. Thus, alloys synthesized in the Si-rich limit would exhibit the high-temperature,  $\alpha$ ThSi2-type structure at room temperature. For this reason, we have designated the low-temperature modification of the phase  $\alpha$ GdSi2 type (distorted  $\alpha$ ThSi2) and the high-temperature modification as  $\alpha$ ThSi2 type. A similar behavior is also observed in other RE-Si systems.

## Nd-Si

#### Thermodynamics

The present evaluators are unaware of any thermodynamic investigation of either the liquid solution or the intermediate phases in the system. In this evaluation, the thermodynamic properties of the liquid were assessed using the experimental solubility data of [84Ere] and the Gibbs energies of fusion for the pure components. The enthalpy of mixing in the liquid can be represented by:

 $\Delta_{\text{mix}}H = X_{\text{Nd}} (1 - X_{\text{Nd}}) (-42.49 + 285.18X_{\text{Nd}} - 385.72X^2_{\text{Nd}} + 160.46X^3_{\text{Nd}} \text{ kJ/mol}$ 

where XNd is the atomic fraction of Nd.

According to this calculation, the liquid solution is slightly endothermic, with a maximum heat absorption of 6.04 kJ/mol at 54.3 at.% Nd. Because these results are based solely on the experimental solubility data of [84Ere], they should be used with caution. Also, in other RE-Si systems, liquid solutions exhibit a strongly exothermic behavior.

The Gibbs energies of fusion for the pure components used in the calculation were represented as a function of temperature in the following form:

 $\Delta fus G(Nd) = 1673.8 + 28.99 T - 4.226 T \ln T \quad kJ/mol$ 

and

 $\Delta_{\text{fus}} G(\text{Si}) = 48527 + 0.497 T + 1.93 \times 10^{-3} T^2$ - 4.372 T ln T - 1.77 × 105 T<sup>-1</sup> kJ/mol

where T is in K. The heat capacities and heats of fusion for the pure components are taken from [77Bar].

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- \* Indicates a key paper.
- # Indicates the presence of a phase diagram.

Nd-Si evaluation contributed by **A.B. Gokhale**, **A. Munitz**, and **G.J. Abbaschian**, Department of Materials Science and Engineering, University of Florida, Gainesville, FL 32611. This work was supported by ASM International under grant No. FG 101-1. Thermodynamic calculations were made using the F\*A\*C\*T computer program at the McGill University, Montreal, Quebec, Canada. The evaluators wish to thank Dr. K.A. Gschneidner, Jr., Director, Rare Earth Information Center, Iowa State University, for his help in providing some of the literature sources. Literature searched through 1984. Professor Abbaschian is the ASM/NIST Data Program Category Editor for binary silicon alloys.

# The Hf-Li (Hafnium-Lithium) System

#### By C.W. Bale Ecole Polytechnique de Montréal

### **Equilibrium Diagram**

The assessed Hf-Li phase diagram is shown in Fig. 1. There are no published data for the Hf-Li phase diagram. By analogy with Li-Ti and Li-Zr and with the other alkali metal-group IV A systems, it is probable that the system is almost completely immiscible in both the solid and liquid states.

If the solubilities are very limited, it follows from thermodynamic considerations that the univariant temperatures in the phase diagram are virtually identical

